

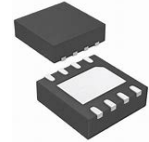


1W,28V Plastic RF LDMOS Gain Block

ITEH40001P3

Description

The ITEH40001P3 is a 1-watt, highly rugged, high linear, LDMOS gain block, designed for any applications at frequencies up to 4GHz, in 6*5mm DFN plastic package, supporting surface mounted on PCB through high density grounding vias.



General broadband reference design:

- Sub 1GHz VHF and UHF: 100-1000MHz
 - L band 1-2GHz
 - S band: 2-3GHz, 3-4GHz
- *: Narrower band reference design upon request

Suitable Applications

- Driver or pre-driver of PA lineup
- 2nd or 3rd stage of LNA lineup

Table 1. Maximum Ratings

| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------------|------|
| Drain--Source Voltage | V_{DSS} | +65 | Vdc |
| Gate--Source Voltage | V_{GS} | -10 to +10 | Vdc |
| Operating Voltage | V_{DD} | +28 | Vdc |
| Storage Temperature Range | T_{stg} | -65 to +150 | °C |
| Case Operating Temperature | T_c | +150 | °C |
| Operating Junction Temperature | T_J | +225 | °C |

Table 2. Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|-----------------|-------|------|
| Thermal Resistance, Junction to Case $T_C = 85^\circ\text{C}$, $P_{out} = 1\text{W}$ 2.1GHz | $R_{\theta JC}$ | 20 | °C/W |

Table 3. ESD Protection Characteristics

| Test Methodology | Class |
|-------------------------------------|---------|
| Human Body Model (per JESD22--A114) | Class 2 |

Table 4. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

DC Characteristics

| | | | | | |
|---|---------------|---|----|---|---------------|
| Drain-Source Voltage $V_{GS} = 0$, $I_{DS} = 100\mu\text{A}$ | $V_{(BR)DSS}$ | | 65 | | V |
| Zero Gate Voltage Drain Leakage Current ($V_{DS} = 28\text{V}$, $V_{GS} = 0\text{V}$) | I_{DSS} | — | — | 1 | μA |
| Gate--Source Leakage Current ($V_{GS} = 11\text{V}$, $V_{DS} = 0\text{V}$) | I_{GSS} | — | — | 1 | μA |

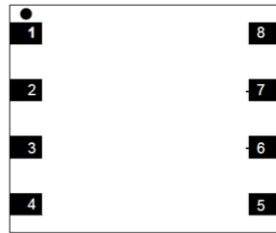


| | | | | | |
|---|--------------|---|-----|---|---|
| Gate Threshold Voltage ($V_{DS} = 28V, I_D = 600 \mu A$) | $V_{GS(th)}$ | — | 2 | — | V |
| Gate Quiescent Voltage ($V_{DD} = 28V, I_D = 70mA$, Measured in Functional Test) | $V_{GS(Q)}$ | — | 2.8 | — | V |

Load Mismatch (In Innogrations Test Fixture, 50 ohm system): $V_{DD} = 28Vdc, I_{DQ} = 70 mA, f = 2100 MHz$

| | |
|---------------------------------------|-----------------------|
| VSWR 10:1 at 1W pulse CW Output Power | No Device Degradation |
|---------------------------------------|-----------------------|

Pin Configuration and Description(Top view)

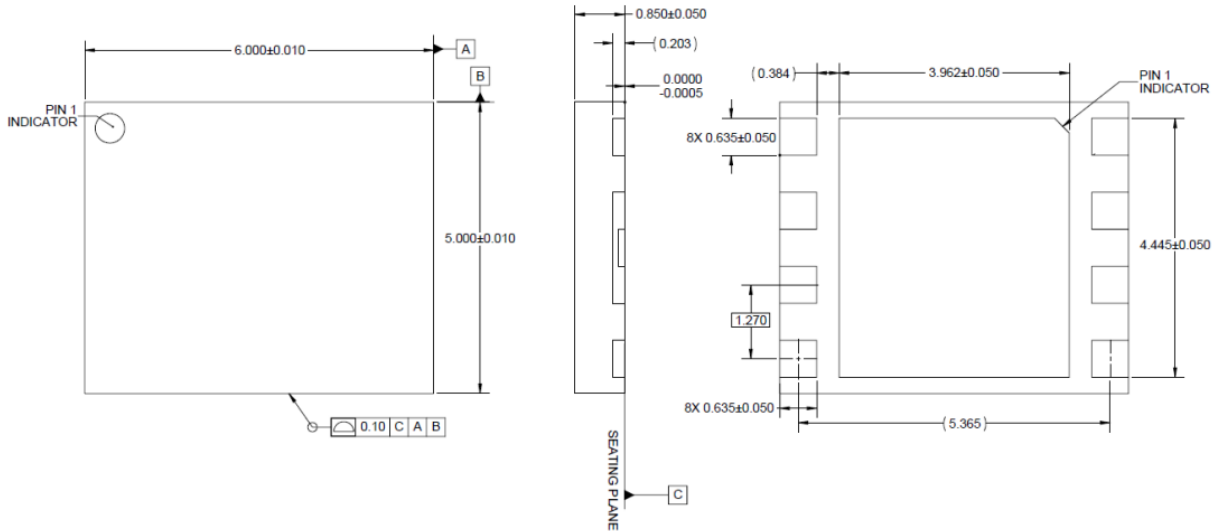


| Pin No. | Symbol | Description |
|----------------|-------------|--|
| 1,2,3,4 | RF IN/VGS | Gate Bias/RF Input |
| 5,6, 7,8 | RF OUT /VDS | RF Output, Drain Bias |
| Backside metal | GND | DC/RF Ground. Must be soldered to EVB ground plane over array of vias for thermal and RF performance. Solder voids under Pkg Base will result in excessive junction temperatures causing permanent damage. |



Package

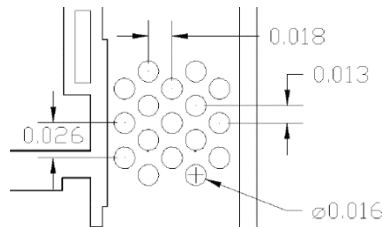
6*5 DFN Package



Notes:

1. All dimensions are in mm. Otherwise noted, the tolerance is ± 0.1 mm.
2. Package leads are gold plated.
3. Part is mold encapsulated.

Recommended vias layout: (all in inches)



Revision history

Table 7. Document revision history

| Date | Revision | Datasheet Status |
|-----------|----------|-----------------------|
| 2024/9/11 | Rev 1.0 | Preliminary Datasheet |

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